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"VAPOR TRANSPORT MECHANISMS"

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Prepared For:

George C. Marshall Space Flight Center
Marshall Space Flight Center, Alabama 35812

August 7, 1978

Principal Investigator:

Dr. Gary L. Workman

Athens State College
Athens, Alabama 35611
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ABSTRACT

The Raman scattering furnace for investigating vapor transport mechanisms has been completed and checked out. Preliminary experiments demonstrate that a temperature resolution of \pm 5^\circ C is possible with this system operating in a backscatter mode. In the experiments presented here with the GeI\textsubscript{4} plus excess Ge system at temperatures up to 600^\circ C, only the GeI\textsubscript{4} band at 150 cm\textsuperscript{-1} has been observed. Further experiments are in progress to determine if GeI\textsubscript{2} does become the major vapor species above 440^\circ C.
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INTRODUCTION

The use of chemical vapor transport for the growth of single crystalline materials has increased considerably in recent years. A number of materials of varying degrees of complexity, such as $\text{Gd}_4\text{GeS}_6$ or $\text{GeSe}_4$, have been grown using chemical vapor transport techniques. The determination of the proper experimental conditions for good crystal growth is performed primarily by trial and error, even today. A significant portion of the research carried out in chemical vapor transport experiments is primarily concerned with developing a basic understanding of the critical parameters in the chemical vapor transport of single crystal materials. A large part of the driving force for studying vapor transport mechanisms has been due to high purity electronic materials grown using this technique and also due to some interesting results from chemical vapor transport experiments performed in a microgravity environment on Skylab and ASTP Orbital Space Flights by Weidemeier. These flight experiments studied the vapor transport of several combinations of germanium compounds (GeSe, GeTe, GeS) using either germanium tetraiodide or germanium tetrachloride for the transport agent. In all cases the transport rates were significantly greater than predicted from either experimentally extrapolated data or from the calculations of Weidemeier using several generally accepted methods based on models proposed by Schafer, Lever, and others.
Mandel\textsuperscript{7}, and Faktor\textsuperscript{7}. The crystalline quality of the crystals grown in the microgravity environment was superior to those grown on the ground using the same methods, even with the higher than expected transport rates. Since no satisfactory explanation exists for the increased microgravity transport, it is generally felt that we still need to know more about the basic fundamentals of chemical vapor transport phenomena. In order to contribute some information about the chemistry involved in such experiments we have attempted to determine more accurately the gaseous compositions and temperature of chemical vapor transport systems using laser Raman spectroscopic techniques. This report is concerned primarily with the results obtained with GeI\textsubscript{4}-Ge system, particularly in the temperature measurements, using laser Raman techniques.
BACKGROUND

The literature contains a number of experimental studies dealing with the germanium iodine system. The treatise by Rolston presents an excellent background on the chemistry of the system, as well as the inconsistencies in some observations of the complex equilibria occurring at high temperatures. The most consistent data which indicated that the important disproportionation reaction

\[(1) \text{GeI}_4(v) + \text{Ge}(s) \rightarrow 2 \text{GeI}_2(v)\]

would shift directions around 440°C was presented by Lever. The thermodynamic analysis of Lever's work also allowed him to determine the equilibrium constants of reaction (1) above as well as for:

\[(2) \text{GeI}_4(v) = \text{GeI}_2(v) + \frac{1}{2} \text{I}_2(v)\]

It was determined that reaction (1) should be the dominating process in the chemical vapor transport of germanium via the iodides. The thermodynamic data of Lever's has been the most widely accepted data. More consideration of this data is presented in a later section where our calculations also predicted reaction (1) to be the most predominant process at higher temperatures.

In its most obvious sense reaction (1) indicates that GeI₄(v) can take up Ge(s) and transport the germanium as GeI₂, and then deposit Ge at the cooler end of the temperature gradient. The simplicity of the process should enable reaction (1) to be demonstrated either experimentally or theoretically to predict
the observed data in micro-gravity. Unfortunately it does not.

The analytical techniques which were considered for the experimental identification of the equilibrium composition included mass spectrometry, optical absorption, infra-red absorption, and laser Raman spectroscopy. Laser Raman spectroscopy was chosen, since it was the only technique which could be used with the particular type of furnace used in this work. Several advantages of laser Raman spectroscopy are that the signal is proportional to the concentration, the frequency shift can be used to identify the molecular species, and that the temperature of the gas can be determined internally.

The theory of Raman Spectroscopy and its many applications has been treated by many authors. For now we are primarily concerned with two functional relationships dealing with Raman scattering intensities versus concentration and temperature. For a definition of the terms used throughout this report we refer to Figure 1. When monochromatic radiation of frequency \( \nu_e \) passes through a nonabsorbing medium, the scattered light which emanates from the excitation region can posses new frequencies depending upon the gas composition. Dr. C.V. Raman demonstrated this effect in 1928 and since that time the process is identified as Raman scattering or Raman spectroscopy. As seen in Figure 1, the scattered frequencies can be described by their frequency shifts from \( \nu_e \). For instance, this example illustrates the observed frequencies \((\nu_e - \Delta \nu_b)\), \((\nu_e - \Delta \nu_a)\), \(\nu_e\), \((\nu_e - \Delta \nu_a)\), and \((\nu_e + \Delta \nu_b)\); listed in order of increasing frequency.
or decreasing wavelength. The observed frequencies smaller than $\nu_e$ are called Stokes scattering while the observed frequencies larger than $\nu_e$ are called anti-Stokes scattering. The scattered radiation having frequency $\nu_e$ (unshifted) is called Rayleigh scattering and represents the largest portion of the scattered radiation by a factor of about $10^6$.

The functional relationship used to derive intensity and compositional relationships is given by:

$$I_i = K (\nu_e + \Delta \nu_i)^4 I_e \rho \sigma_i, T$$

where

- $K$ - Constant whose value depends upon experimental optics
- $\nu_e$ - Laser excitation frequency
- $\Delta \nu_i$ - Raman frequency shift for component $i$
- $I_e$ - Excitation laser intensity
- $\rho$ - Number density of molecular species $i$
- $\sigma_i, T$ - Raman scattering cross-section for species $i$ at temperature $T$

The Raman data obtained with the GeI$_4$-Ge samples will thus provide the following information. From the frequency shift of the observed Raman signal, the identity of the scattering molecule can be deduced. Upon taking the ratio of the anti-Stoke signal to the Stokes signal, the temperature can be obtained with the following relation:

$$R = \frac{I (\nu_e - \Delta \nu_i)}{I (\nu_e + \Delta \nu_i)} = \frac{(\nu_e + \Delta \nu_i)^4}{(\nu_e + \Delta \nu_i)^4} \exp \left( -\frac{h \Delta \nu_i}{k T} \right)$$
The accuracy of the anti-Stokes/Stokes method is improved when integrated peak areas are used, rather than just peak blights. Since the Raman signals are usually quite weak compared to certain argon emission lines which occur in the same spectral regions as the desired Raman bands, integrated areas should represent a more accurate definition of the peak profile also.

The thermodynamics of chemical vapor transport reactions can be very complicated when all equilibria are taken into consideration. For example, a temperature dependent process such as the reactions of interest relies primarily upon the differences in equilibrium constants for the dominant processes. In the case of the GeI₄-Ge system we need to include the reaction

(5) \( I_2 = 2I \)

with reaction (1) and (2) in order to describe the system appropriately. Calculations of their respective equilibrium constants versus temperature is given in Figure 2. Note the dominance of reaction (1) in terms of magnitude of the equilibrium constant and the large temperature dependence of the reaction. A simple calculation of the species concentration at various temperature when an ampoule of 47 cm³ volume is initially filled with 0.19 grams GeI₄ + excess germanium is shown in Figure 2. Note that the total pressure in the tube should be predominantly \( t \) GeI₄ above 500°C. These predicted values were calculated using Lever's thermodynamic values. One objective of this experimental work is to confirm or provide alternative values for these thermodynamic values for the Ge-I system.
EXPERIMENTAL CONSIDERATIONS

The principal components required for obtaining Raman signature of the vapor transport gas are shown in Figure 4. The physical arrangement of the components can be seen in Figure 5. The laser Raman excitation at 488.0 or 514.5 nanometer wavelength is provided by an Argon Ion laser. Typically, 1 watt of power is used in these experiments. The 0.5 milliwatt helium neon laser is used for aligning the sample tube with the monochromator and optical train. The typical chemical vapor transport gradient to be established is across the length of the tube. In order to satisfy that requirement a three zone furnace with each zone being independently monitored and heated through proportional controllers was fabricated as seen in Figure 6. The internal structure was fabricated with a high temperature fiber material with the heating elements already enclosed, which was purchased from Aten Industries. Thus, the three zone furnace was constructed from a set of three of these assemblies, cemented together with a high temperature binder.

Since this phase of the study required an isothermal environment, a housing constructed of stainless steel with a single aperture for the laser beam to enter and the Raman signal to leave was utilized in order to eliminate thermal gradients. Thermocouples located at various points inside the housing enabled us to determine the temperature at those locations. Small adjustments in the heating controls could then linearize the thermal
characteristics of the sample tube. These features are shown in Figure 7.

The optical train uses beam steering components to direct the beam into the sample tube. The backscatter optics then collect the Raman scattered light from the sample tube and transmit it to the monochromator slit, shown in Figure 8. The image focused onto the monochromator slit is fairly closely matched to the optical system in the spectrograph. Both spherical and cylindrical optics have been used for focusing the laser excitation beam into the sample tube. The cylindrical lens has an advantage in that the Raman scattered image matched the slit better than the point source of the spherical lens, and made alignment simpler.

The monochromator used in this work was a Spex 14018 double monochromator with 1800 lines/mm gratings. The Raman signal was detected with a RCA C31034 photomultiplier tube cooled to -140°C. Photon counting electronics were used to measure the Raman signals. Both a Spex model DPC-2 and a Princeton Applied Research model 1110 photon counter were used for the data shown in this report. Typically the dark count was less than 100 counts/sec.
EXPERIMENTAL RESULTS

Examples of spectra obtained with this system are given in Figure 9 and 10 for iodine vapor. The spectra have been obtained both in ampoules containing only iodine and in the ampoules containing GeI$_4$ with excess germanium. The temperature determinations inside the ampoule should be readily done with I$_2$ vapor. Unfortunately we did not obtain success with the anti-Stokes/Stokes ratio when we used the peak height approach with 488.0 n.m. excitation. Excitation with the 514.5 n.m. line causes fluorescence and is not reliable in our application. Later experiments with the GeI$_4$ tubes were not much better, since the I$_2$ concentration was only large enough for fluorescence to be detected. This was expected from the calculated concentration profiles in Figure 3. The spectra shown in Figure 9 is fluorescence spectra from an iodine ampoule and is a very large signal. Correspondingly Figure 10 shows the profiles obtained for Resonance Raman Scattering with the 488.0 n.m. excitation. An excellent discussion of the differences in these spectra is given by Bernstein; however, these differences are not really pertinent to our results.

Spectra of GeI$_4$ which have been correlated with the reported data of Stammreich, H. are given in Figures 11 and 12 for the Stokes and the anti-Stokes, respectively. These were obtained with the 488.0 n.m. line and are rather weak. Similar spectra obtained with the 514.5 n.m. line, as shown in Figure 13, has
fluorescence bands of I₂ as well as GeI₄. None of the spectra obtained with the GeI₄ plus excess germanium tube showed any peaks with frequency shifts in the region of 115 cm⁻¹ as reported in our previous work. Figure 14 shows the band observed from solid GeI using 488.0 n.m. radiation in the original work with the transparent furnace.

The representative spectra shown in the preceding figures were fairly consistent in the temperature range from 250-600°C. The most prominent feature obtained from Raman scattering signals was the band around 150 cm⁻¹ from the excitation line. We obtained this band using both the 488.0 and the 514.5 nanometer excitation wavelengths. This band has been assigned as the totally symmetric stretching fundamental for GeI₄ and is shifted slightly from the 160 cm⁻¹ reported by Stammreich. There is also observed a small temperature shift associated with the band maximum as indicated in Table 1. This small shift is peak maximum with the temperature implies that GeI₄ provides the Raman signal around 150 cm⁻¹ for complete temperature range from 250-600°C. Except for the band observed at 213 cm⁻¹, which is assigned to I₂, no bands which can definitely be assigned to GeI₂ were observed.

In addition to the molecular identification applications of Raman scattering, temperature measurements of the vapor inside the ampoule were made using the anti-Stokes/Stokes ratio technique.
Both the I band at 213 cm\(^{-1}\) and the GeI\(_4\) band at 150 cm\(^{-1}\) were used for the temperature measurements using equation (4), but only the data with 488.0 n.m. excitation proved to be reliable. Table 1 lists some of these observations which were measured by band integration techniques. For the bands which lie fairly close to the excitation peak, the peak height measurements did not satisfy equation (4) consistently; so we then used integration of the band profile exclusively. The only disadvantage encountered is the long integration times required for measurable lineshapes.

The data in Table 1 also demonstrates the temperature resolution obtainable with this system. The use of long integration times (5-20 seconds per point) will allow about \(\pm 5\) degrees resolution. This is probably the best we can be assured of maintaining in the backscatter mode of operation.
DISCUSSION

The results obtained with these experimental conditions does allow us to determine temperature profiles and species identification in isothermal ampoule experiments. These results can be extrapolated to include quantitative measurements of concentration, if calibrations have been properly assessed, and also to include vapor transport experiments themselves. Due to the as yet unconfirmed GeI\textsubscript{4} to GeI\textsubscript{2} spectral shift as expected by our calculations, we cannot define the equilibria of the Ge-I system sufficiently to determine why the Raman spectra of GeI\textsubscript{2} did not occur.

The only experimental disadvantage to the Raman scattering technique is that the Raman signals can be extremely weak and using the backscatter mode of operation can be difficult if the system is not properly aligned. The chief advantage to using the backscatter mode is that the vapor absorption of the Raman signal is reduced. Since I\textsubscript{2}, GeI\textsubscript{4}, and GeI\textsubscript{2} all absorb in the 500 n.m. region, this was considered necessary for our initial experiments. If the vapor media is not absorbing in the visible then the perpendicular scatter mode is to be preferred.

The experimental technique has progressed sufficiently so that we know the furnace works properly and the Raman signals are available for temperature and concentration measurements.
Certain laser environmental controls such as constant voltage levels and uniform water flow are also being incorporated for consistent excitation intensities. In the events to follow this work we intend to work with one of Weidemeiers' ampoules from the Apollo-Soyuz flight, which has a stoichiometry that has transported and allow us to determine if the Raman bands are different from our first observations. The identification of GeI$_2$ in these experiments and confirmation of Lever's work still remains an objective of this work.
References


ACKNOWLEDGEMENTS

I wish to acknowledge the work of Mike Perry and Mike Lenox from Athens State College for various phases of this work and Jim Zwiener and Dr. Mirt Davidson of Marshall Space Flight Center for their assistance in this work. I also wish to thank Mrs. Pat Craig for typing this report.
Figure 2: TEMPERATURE VARIATION OF $K_p$ FOR THE THREE DOMINANT REACTIONS IN Ge-I SYSTEM.
Figure 3: EQUILIBRIUM PARTIAL PRESSURES OF Ge I SPECIES IN Ge$\textsubscript{4}$ + Ge AMPOULE (0.19 GMS Ge + EXCESS GMS Ge) USING LEVER'S VALUES FOR $K_p$.
CVT RAMAN PROBE APPARATUS
PHOTO OF MAJOR COMPONENTS

CVT RAMAN PROBE APPARATUS
PHOTO OF OPTICAL COMPONENTS
Figure 6: Schematic of Laser Probe and Backscatter Collection Optics
Figure 7:
RAMAN SLIT FURNACE

REAR CYLINDRICAL HEATER

VIEW AA

FIXED FURNACE SLITS

FRONT FLAT HEATER

MOVABLE FURNACE SLIT

TOP ZONE

TEMPERATURE CONTROL T/C'S

MIDDLE ZONE

ISOTHERMAL SAMPLE HOLDER

BOTTOM ZONE

HEAT REJECTION LASER RAMAN PROBE WINDOWS
Figure 8: ISOTHERMAL SAMPLE HOLDER

- CERAMIC SUPPORT ROD
- THERMAL COUPLES LEADS (T/C)
- CERAMIC T/C GUIDES
- CERAMIC T/C TUBES TWO HOLES
- S.S. OUTER SHELL
- MIDDLE, FRONT & REAR T/C
- LASER RAMAN PROBE PORT
- S.S. INNER SHELL
- BOTTOM T/C
- THERMAL INSULATION
- QUARTZ SAMPLE TUBE
Spectra showing types of bands observed for iodine with resonance Raman scattering.

**Figure 10:**

- **Antistokes Raman Band for Iodine Vapor Using 4880 Å Laser Excitation**
- **Stokes Raman Band for Iodine Vapor Using 4880 Å Laser Excitation**
Figure 11:
STOKES RAMAN BAND FOR GeI₄ VAPOR
USING 4880 Å LASER EXCITATION
Figure 12:
ANTISTOKES RAMAN BAND FOR GeI₄ VAPOR
USING 4880 Å LASER EXCITATION
Figure 15: Anti-Stokes/Stokes ratio for Raman band at 150 m", laser excitation using the 488.0 nm line.
<table>
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<tr>
<th>RUN NUMBER</th>
<th>TEMPERATURE CENTRIGRADE</th>
<th>RAMAN SHIFT CM⁻¹</th>
<th>EXCITATION WAVELENGTH NM</th>
<th>CALCULATED A/S RATIO</th>
<th>MEASURED A/S RATIO (T)</th>
<th>REMARKS</th>
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<tr>
<td>417</td>
<td>253.0</td>
<td>153.7</td>
<td>488.0</td>
<td>0.703</td>
<td>0.693 (234)</td>
<td>WIDE SLITS NOISY BACKGROUND</td>
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<tr>
<td>428</td>
<td>426.0</td>
<td>152.9</td>
<td>488.0</td>
<td>0.778</td>
<td>0.769 (399)</td>
<td>LESS WIDE SLITS GOOD BACKGROUND</td>
</tr>
<tr>
<td>501</td>
<td>451.6</td>
<td>151.8</td>
<td>488.0</td>
<td>0.786</td>
<td>0.841 (659)</td>
<td>OVERLAPPING LASER LINE</td>
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<tr>
<td>502</td>
<td>476.0</td>
<td>151.5</td>
<td>514.5</td>
<td>0.797</td>
<td>1.269</td>
<td>NOISY BACKGROUND CLEAN SIGNALS</td>
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<tr>
<td>503</td>
<td>523.0</td>
<td>151.7</td>
<td>514.5</td>
<td>0.811</td>
<td>1.190</td>
<td>GOOD SIGNALS</td>
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<tr>
<td>504</td>
<td>524.0</td>
<td>151.4</td>
<td>488.0</td>
<td>0.808</td>
<td>0.804 (507)</td>
<td>GOOD BACKGROUND OVERLAPPING LASER LINE</td>
</tr>
<tr>
<td>505</td>
<td>304.0</td>
<td>153.0</td>
<td>488.0</td>
<td>0.729</td>
<td>0.707 (259)</td>
<td>NOISY SIGNAL</td>
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<tr>
<td>510</td>
<td>471.0</td>
<td>151.1</td>
<td>488.0</td>
<td>0.793</td>
<td>0.830 (609)</td>
<td>POOR RESOLUTION OVERLAPPING LASER LINE</td>
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<tr>
<td>515</td>
<td>585.0</td>
<td>150.4</td>
<td>488.0</td>
<td>0.826</td>
<td>0.821 (571)</td>
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<tr>
<td>606</td>
<td>395.0</td>
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<td>514.5</td>
<td>0.770</td>
<td>1.360</td>
<td>GOOD SIGNAL</td>
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<tr>
<td>607</td>
<td>395.0</td>
<td>152.2</td>
<td>488.0</td>
<td>0.767</td>
<td>0.763 (383)</td>
<td>GOOD BACKGROUND</td>
</tr>
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Table 1. SUMMARY OF EXPERIMENTAL DATA FROM LASER RAMAN SCATTERING FOR TEMPERATURE MEASUREMENT IN Ge-I SYSTEM